

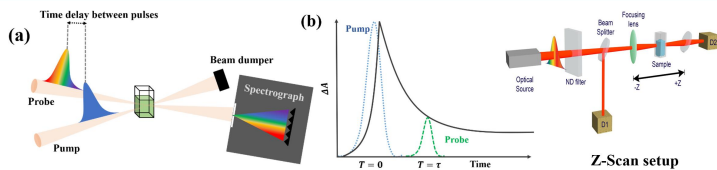
Ultrafast Charge Carrier Dynamics in Two Dimensional Materials

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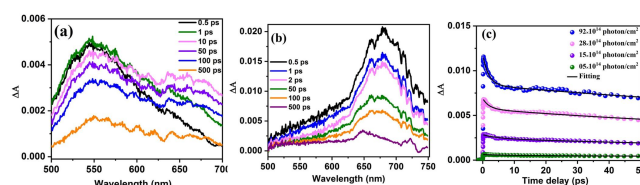
- 2D SnS is a member of emerging layered metal monochalcogenide. Theoretical investigations revealed a sizeable band gap, quantum confinement effect, high carrier mobility and large absorption coefficient in few-layer SnS.
- In ultrathin SnS understanding of elementary quasiparticles and their interaction or dynamics in condensed matter physics system is critical for better energy conversion and photonic applications.
- SnS layers are environmentally, thermally and dynamically stable. Our findings highlight the prospects for the synthesis of ultrathin anisotropic SnS towards the betterment of thermoelectric and photonic devices.

Experimental techniques

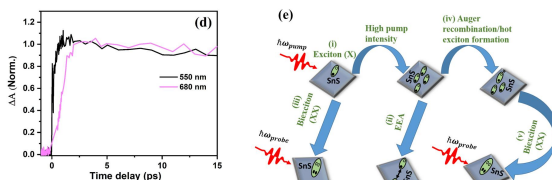
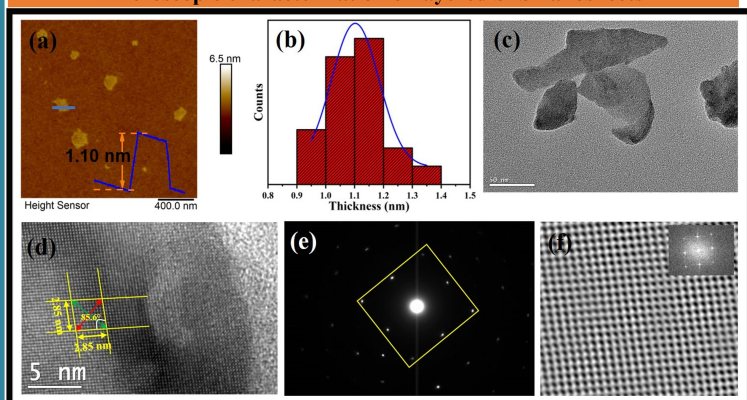


Transient absorption spectroscopy (TAS) setup

Charge carrier dynamics



Microscopic characterization of layered SnS nanosheets



The rate of annihilation of excitons is proportional to the square of the exciton density, N_x

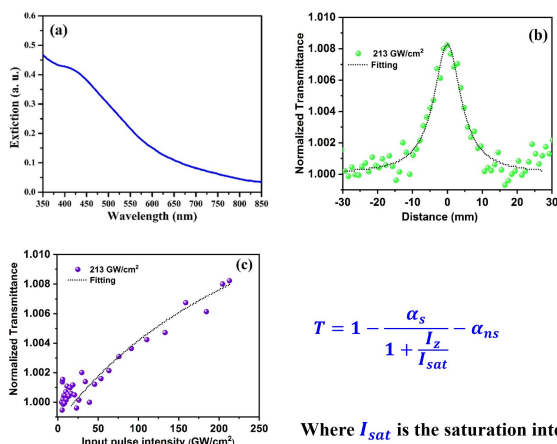
$$\frac{dN_x}{dt} = -kN_x^2$$

$$N_x(t) = \frac{N_0}{1 + kN_0t} + C$$

Annihilation rate $4.34 \times 10^{-4} \text{ cm}^2/\text{s}$

Nonlinear optics in 2D SnS nanosheets, using Z-Scan

Conclusions



$$P(t) = \epsilon_0(\chi^{(1)}E(t) + \chi^{(2)}E^2(t) + \chi^{(3)}E^3(t) + \dots)$$

Here, ϵ_0 is the dielectric permittivity of vacuum, coefficients χ^n are the nth order susceptibilities of the medium

$$T = \frac{1}{\sqrt{\pi}q_0} \int_{-\infty}^{\infty} \ln(1 + q_0 e^{-x^2}) dx$$

For $|q_0| < 1$, the transmittance in terms of peak irradiance can be expressed in summation form as

$$T = 1 - \frac{\alpha_{NL} I_0 L_{eff}}{2\sqrt{2} \left[1 + \left(\frac{z}{z_0} \right)^2 \right]}$$

Here $q_0 = \alpha_{NL} I_0 L_{eff}$, α_{NL} is NLO absorption coefficient

Where I_{sat} is the saturation intensity

(a) Absorption spectra of SnS nanosheets (b) Open aperture (OA) Z-scan curve (c) Normalized transmittance as a function of input pulse intensity.

We successfully conduct liquid phase exfoliation of SnS to obtain ultrathin (~1.15 nm) nanosheets.

Exfoliated ultrathin SnS nanosheets are analyzed by TEM and AFM.

High nonlinear absorption coefficient ($\sim 0.5 \times 10^{-3} \text{ cm/GW}$) and low saturable intensity (570 GW/cm^2) of SnS nanosheets due to strong EEA and absorption of delayed photon make them suitable for ultrafast Q-switching

Our Transient absorption (TA) results reveal rich exciton-exciton and coherent exciton-photon interactions arising from many-particle excited effects in ultrathin SnS.

At higher exciton density, Auger process leads to the formation of hot exciton, which is converted to a biexciton by absorbing another photon of low energy.

This work sheds light on synthesis, nature of the phonon dynamics and nonlinear optical phenomena in 2D materials for futuristic energy conversion and photonic applications

References

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